imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

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Complementary Plastic Power Transistors

NPN/PNP Silicon DPAK For Surface Mount Applications

Designed for low voltage, low-power, high-gain audio amplifier applications.

Features

- High DC Current Gain
- Lead Formed for Surface Mount Applications in Plastic Sleeves (No Suffix)
- Low Collector–Emitter Saturation Voltage
- High Current-Gain Bandwidth Product
- Annular Construction for Low Leakage
- Epoxy Meets UL 94 V-0 @ 0.125 in
- NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Collector-Base Voltage	V _{CB}	40	Vdc
Collector-Emitter Voltage	V _{CEO}	25	Vdc
Emitter-Base Voltage	V _{EB}	8.0	Vdc
Collector Current – Continuous	۱ _C	5.0	Adc
Collector Current – Peak	I _{CM}	10	Adc
Base Current	Ι _Β	1.0	Adc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	12.5 0.1	W W/°C
Total Power Dissipation (Note 1) @ $T_A = 25^{\circ}C$ Derate above 25°C	P _D	1.4 0.011	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C
ESD – Human Body Model	HBM	3B	V
ESD – Machine Model	MM	С	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

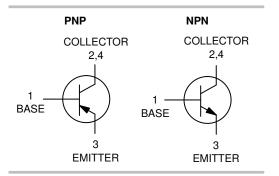
1. These ratings are applicable when surface mounted on the minimum pad sizes recommended.



ON Semiconductor®

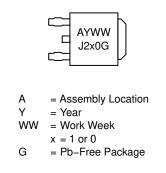
http://onsemi.com

SILICON POWER TRANSISTORS 5 AMPERES 25 VOLTS, 12.5 WATTS





MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

THERMAL CHARACTERISTICS

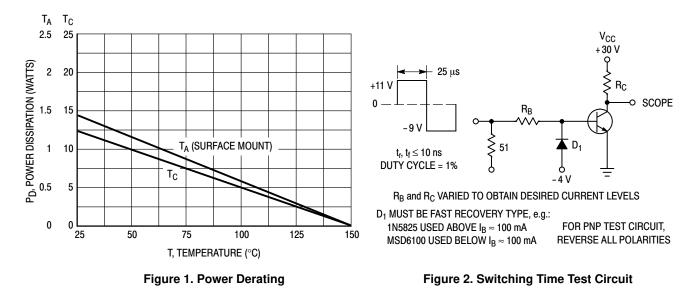
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{ ext{ heta}JC}$	10	°C/W
Thermal Resistance, Junction-to-Ambient (Note 2)	R _{θJA}	89.3	°C/W

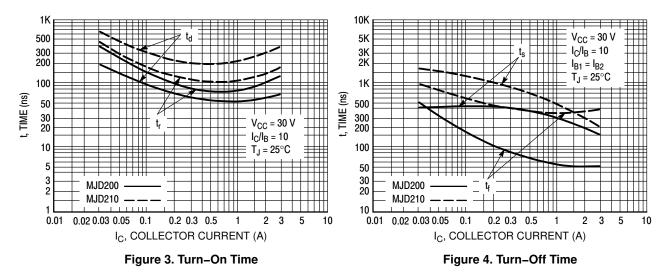
2. These ratings are applicable when surface mounted on the minimum pad sizes recommended.

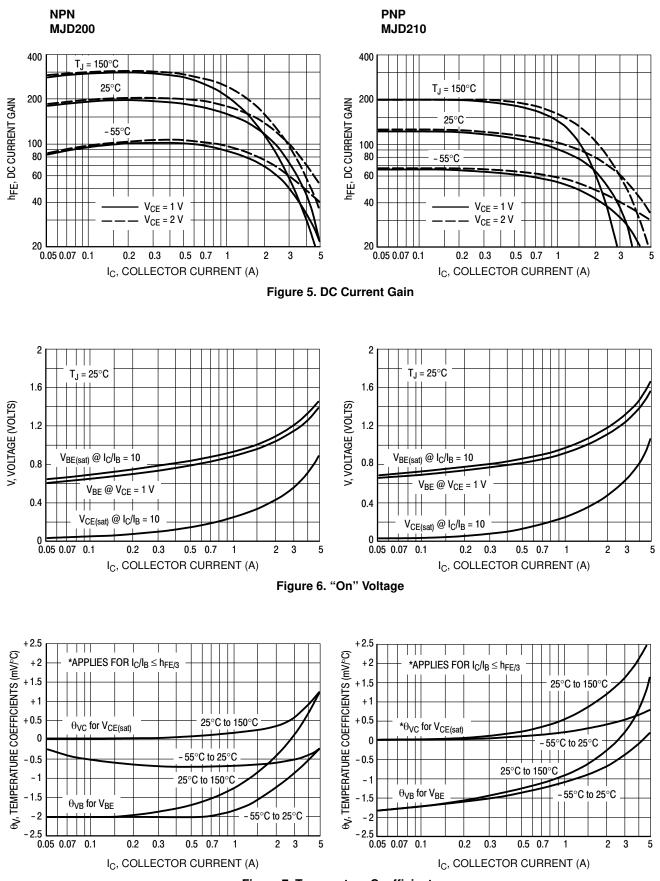
ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS			•	
Collector–Emitter Sustaining Voltage (Note 3) $(I_{C} = 10 \text{ mAdc}, I_{B} = 0)$	V _{CEO(sus)}	25	_	Vdc
	V _{CBO}		100 100	nAdc μAdc
Emitter Cutoff Current ($V_{BE} = 8 \text{ Vdc}, I_C = 0$)	V _{EBO}	-	100	nAdc
ON CHARACTERISTICS			•	
$ C \ Current \ Gain \ (Note 3), \\ (I_C = 500 \ mAdc, \ V_{CE} = 1 \ Vdc) \\ (I_C = 2 \ Adc, \ V_{CE} = 1 \ Vdc) \\ (I_C = 5 \ Adc, \ V_{CE} = 2 \ Vdc) \\ (I_C = 5 \ Adc, \ V_{CE} = 2 \ Vdc) $	h _{FE}	70 45 10	- 180 -	_
	V _{CE(sat)}	- - -	0.3 0.75 1.8	Vdc
Base-Emitter Saturation Voltage (Note 3) (I _C = 5 Adc, I _B = 1 Adc)	V _{BE(sat)}	_	2.5	Vdc
Base-Emitter On Voltage (Note 3) (I _C = 2 Adc, V _{CE} = 1 Vdc)	V _{BE(on)}	_	1.6	Vdc
DYNAMIC CHARACTERISTICS				
Current–Gain – Bandwidth Product (Note 4) ($I_C = 100 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f_{test} = 10 \text{ MHz}$)	f _T	65	-	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 0.1 MHz) MJD200 MJD210, NJVMJD210T4G	C _{ob}	-	80 120	pF

3. Pulse Test: Pulse Width = 300 μ s, Duty Cycle $\approx 2\%$. 4. $f_T = |h_{fe}| \bullet f_{test}$.









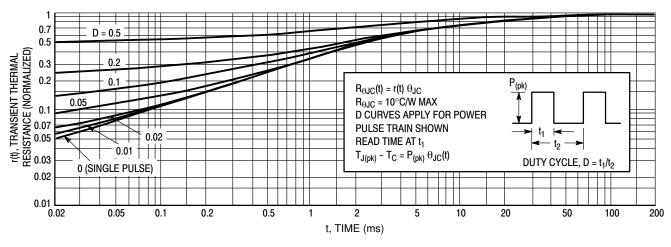


Figure 8. Thermal Response

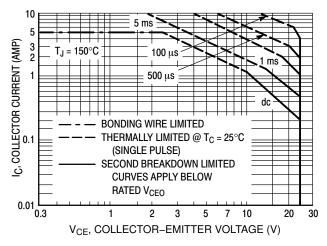


Figure 9. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 9 is based on $T_{J(pk)} = 150^{\circ}C$; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \le 150^{\circ}C$. $T_{J(pk)}$ may be calculated from the data in Figure 8. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

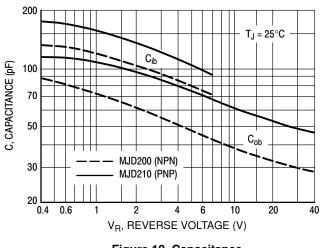


Figure 10. Capacitance

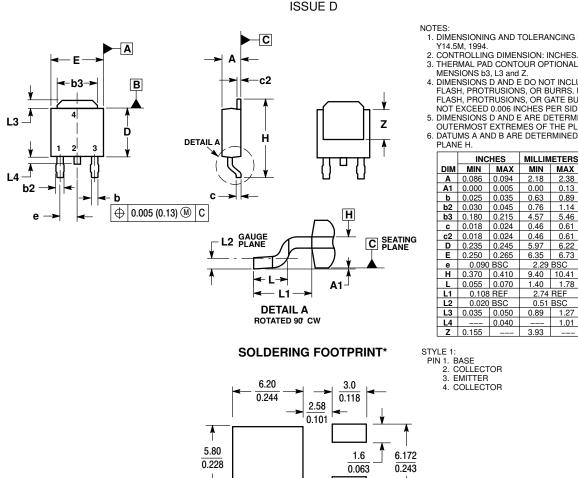
ORDERING INFORMATION

Device	Package Type	Shipping [†]	
MJD200G	DPAK (Pb–Free)	75 Units / Rail	
MJD200RLG	DPAK (Pb–Free)	1,800 / Tape & Reel	
MJD200T4G	DPAK (Pb–Free)	2,500 / Tape & Reel	
MJD210G	DPAK (Pb-Free)	75 Units / Rail	
MJD210RLG	DPAK (Pb–Free)	1,800 / Tape & Reel	
MJD210T4G	DPAK (Pb–Free)	2,500 / Tape & Reel	
NJVMJD210T4G*	DPAK (Pb–Free)	2,500 / Tape & Reel	

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. *NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP

Capable

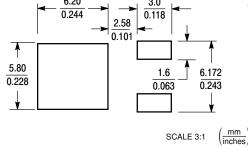
PACKAGE DIMENSIONS



DPAK CASE 369C ISSUE D

- 1. DIMENSIONING AND TOLERANCING PER ASME
- THERMAL PAD CONTOUR OPTIONAL WITHIN DI-MENSIONS b3, L3 and Z.
- MENSIONS DS, LS and Z. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.
- DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
- DATUMS A AND B ARE DETERMINED AT DATUM

	INCHES		ICHES MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.086	0.094	2.18	2.38
A1	0.000	0.005	0.00	0.13
b	0.025	0.035	0.63	0.89
b2	0.030	0.045	0.76	1.14
b3	0.180	0.215	4.57	5.46
С	0.018	0.024	0.46	0.61
c2	0.018	0.024	0.46	0.61
D	0.235	0.245	5.97	6.22
E	0.250	0.265	6.35	6.73
е	0.090 BSC		2.29 BSC	
н	0.370	0.410	9.40	10.41
L	0.055	0.070	1.40	1.78
L1	0.108 REF		2.74 REF	
L2	0.020 BSC		0.51 BSC	
L3	0.035	0.050	0.89	1.27
L4		0.040		1.01
Z	0.155		3.93	



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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